

MOSFETs Silicon N-Channel MOS

# SSM3K336R

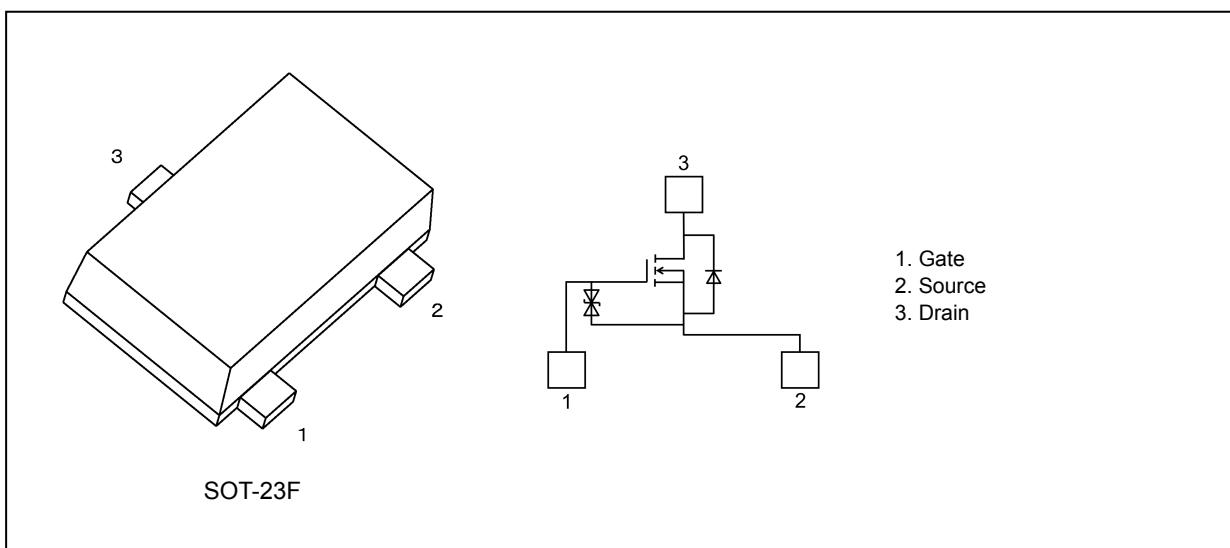
## 1. Applications

- Power Management Switches
- DC-DC Converters

## 2. Features

- (1) 4.5 V gate drive voltage.
- (2) Low drain-source on-resistance  
:  $R_{DS(ON)} = 95 \text{ m}\Omega$  (max) (@ $V_{GS} = 10 \text{ V}$ )  
 $R_{DS(ON)} = 140 \text{ m}\Omega$  (max) (@ $V_{GS} = 4.5 \text{ V}$ )

## 3. Packaging and Internal Circuit



Start of commercial production  
2012-07

#### 4. Absolute Maximum Ratings (Note) (Unless otherwise specified, $T_a = 25^\circ\text{C}$ )

Characteristics	Symbol	Rating	Unit
Drain-source voltage	$V_{DSS}$	30	V
Gate-source voltage	$V_{GSS}$	$\pm 20$	
Drain current (DC)	$I_D$	3	A
Drain current (pulsed)	$I_{DP}$	8	
Power dissipation	$P_D$	1	W
Power dissipation ( $t \leq 10 \text{ s}$ )	$P_D$	2	W
Channel temperature	$T_{ch}$	150	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Note 1: Ensure that the channel temperature does not exceed  $150^\circ\text{C}$ .

Note 2: Pulse width (PW)  $\leq 10 \text{ ms}$ , duty  $\leq 1\%$

Note 3: Device mounted on a FR4 board.(25.4 mm  $\times$  25.4 mm  $\times$  1.6 mm, Cu Pad: 645 mm $^2$ )

Note: The MOSFETs in this device are sensitive to electrostatic discharge. When handling this device, the worktables, operators, soldering irons and other objects should be protected against anti-static discharge.

Note: The channel-to-ambient thermal resistance,  $R_{th(ch-a)}$ , and the power dissipation,  $P_D$ , vary according to the board material, board area, board thickness and pad area. When using this device, be sure to take heat dissipation fully into account.

#### 5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-ambient thermal resistance (Note 1)	$R_{th(ch-a)}$	125	$^\circ\text{C/W}$

Note 1: Device mounted on an 25.4 mm  $\times$  25.4 mm  $\times$  1.6 mm FR4 glass epoxy board (Cu pad: 645 mm $^2$ )

## 6. Electrical Characteristics

### 6.1. Static Characteristics (Unless otherwise specified, $T_a = 25^\circ\text{C}$ )

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	$I_{GSS}$	$V_{GS} = \pm 20\text{ V}, V_{DS} = 0\text{ V}$	—	—	$\pm 10$	$\mu\text{A}$
Drain cut-off current	$I_{DSS}$	$V_{DS} = 30\text{ V}, V_{GS} = 0\text{ V}$	—	—	1	
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = 10\text{ mA}, V_{GS} = 0\text{ V}$	30	—	—	$\text{V}$
Drain-source breakdown voltage (Note 1)	$V_{(BR)DSX}$	$I_D = 10\text{ mA}, V_{GS} = -20\text{ V}$	15	—	—	
Gate threshold voltage (Note 2)	$V_{th}$	$V_{DS} = 10\text{ V}, I_D = 0.1\text{ mA}$	1.3	—	2.5	
Drain-source on-resistance (Note 3)	$R_{DS(\text{ON})}$	$I_D = 2.0\text{ A}, V_{GS} = 10\text{ V}$	—	67	95	$\text{m}\Omega$
		$I_D = 1.0\text{ A}, V_{GS} = 4.5\text{ V}$	—	100	140	
Forward transfer admittance (Note 3)	$ Y_{fs} $	$V_{DS} = 10\text{ V}, I_D = 1.0\text{ A}$	2.5	5	—	$\text{S}$

Note 1: If a reverse bias is applied between gate and source, this device enters  $V_{(BR)DSX}$  mode. Note that the drain-source breakdown voltage is lowered in this mode.

Note 2: Let  $V_{th}$  be the voltage applied between gate and source that causes the drain current ( $I_D$ ) to below (0.1 mA for this device). Then, for normal switching operation,  $V_{GS(\text{ON})}$  must be higher than  $V_{th}$ , and  $V_{GS(\text{OFF})}$  must be lower than  $V_{th}$ . This relationship can be expressed as:  $V_{GS(\text{OFF})} < V_{th} < V_{GS(\text{ON})}$ .

Take this into consideration when using the device.

Note 3: Pulse measurement.

### 6.2. Dynamic Characteristics (Unless otherwise specified, $T_a = 25^\circ\text{C}$ )

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Input capacitance	$C_{iss}$	$V_{DS} = 15\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$	—	126	—	$\text{pF}$
Reverse transfer capacitance	$C_{rss}$		—	8	—	
Output capacitance	$C_{oss}$		—	26	—	
Switching time (turn-on time)	$t_{on}$	$V_{DD} = 15\text{ V}, I_D = 0.5\text{ A}$ $V_{GS} = 0\text{ to }4.5\text{ V}, R_{GS} = 10\Omega$ Duty $\leq 1\%$ , Input: $t_r, t_f < 5\text{ ns}$ Common source, See Chapter 6.3	—	7	—	$\text{ns}$
Switching time (turn-off time)	$t_{off}$		—	8	—	

### 6.3. Switching Time Test Circuit

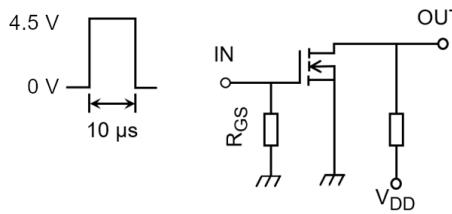


Fig. 6.3.1 Test Circuit of Switching Time

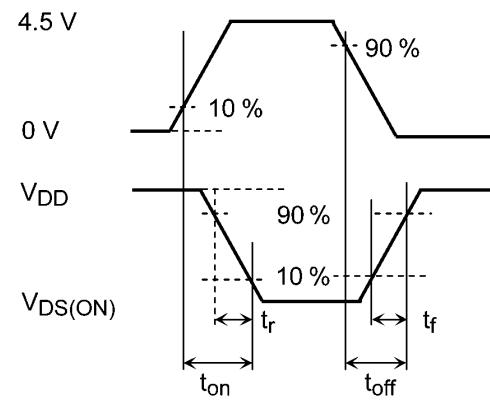


Fig. 6.3.2 Input Waveform/Output Waveform

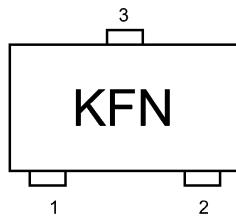
### 6.4. Gate Charge Characteristics (Unless otherwise specified, $T_a = 25^\circ\text{C}$ )

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Total gate charge (gate-source plus gate-drain)	$Q_g$	$V_{DD} = 15\text{ V}, V_{GS} = 4.5\text{ V}, I_D = 3.0\text{ A}$	—	1.7	—	$\text{nC}$
Gate-source charge 1	$Q_{gs1}$		—	0.8	—	
Gate-drain charge	$Q_{gd}$		—	0.7	—	

**6.5. Source-Drain Characteristics (Unless otherwise specified,  $T_a = 25^\circ\text{C}$ )**

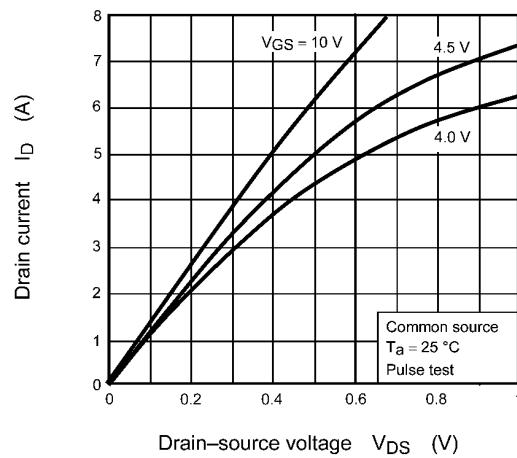
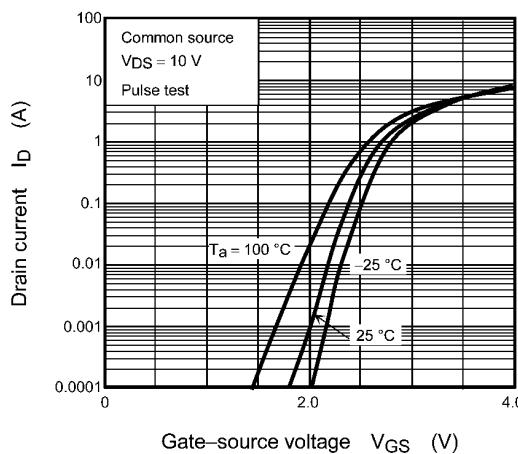
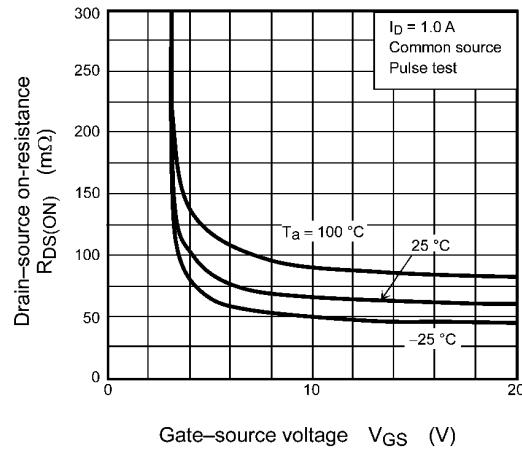
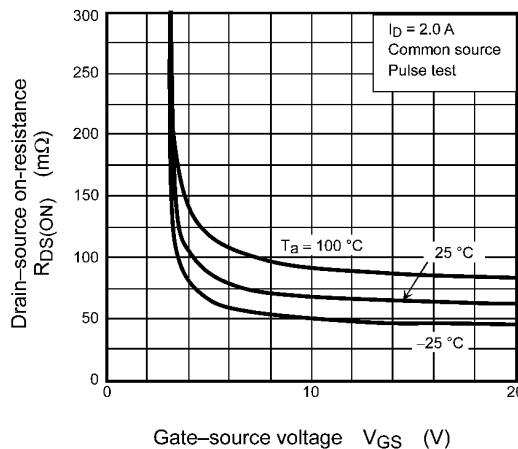
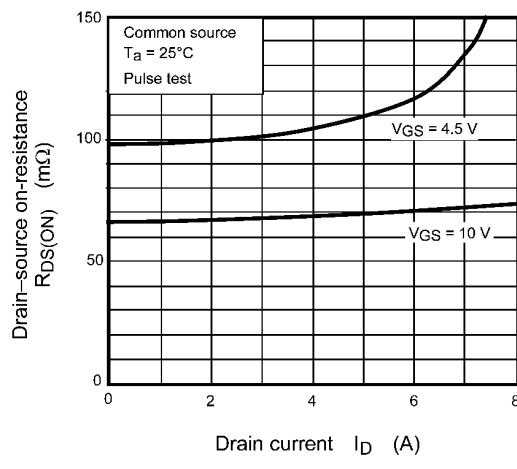
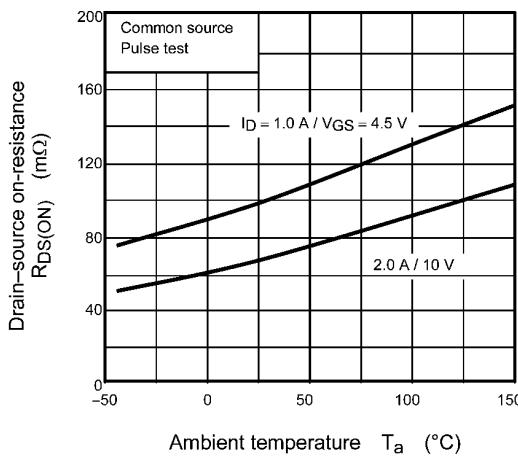
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Diode forward voltage (Note 1)	$V_{DSF}$	$I_{DR} = 3.0 \text{ A}$ , $V_{GS} = 0 \text{ V}$	—	0.89	1.2	V

Note 1: Pulse measurement.

**7. Marking**

**Fig. 7.1 Marking**

## 8. Characteristics Curves (Note)

Fig. 8.1  $I_D$  -  $V_{DS}$ Fig. 8.2  $I_D$  -  $V_{GS}$ Fig. 8.3  $R_{DS(ON)}$  -  $V_{GS}$ Fig. 8.4  $R_{DS(ON)}$  -  $V_{GS}$ Fig. 8.5  $R_{DS(ON)}$  -  $I_D$ Fig. 8.6  $R_{DS(ON)}$  -  $T_a$

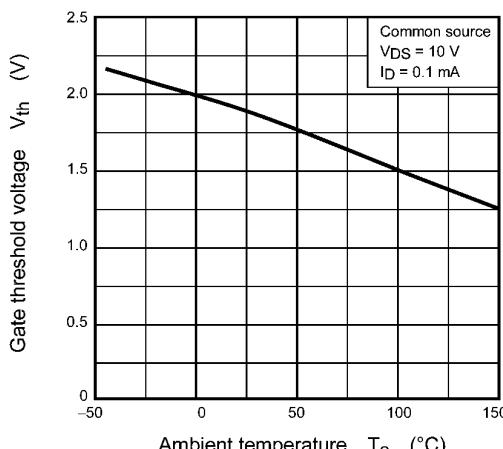


Fig. 8.7  $V_{th}$  -  $T_a$

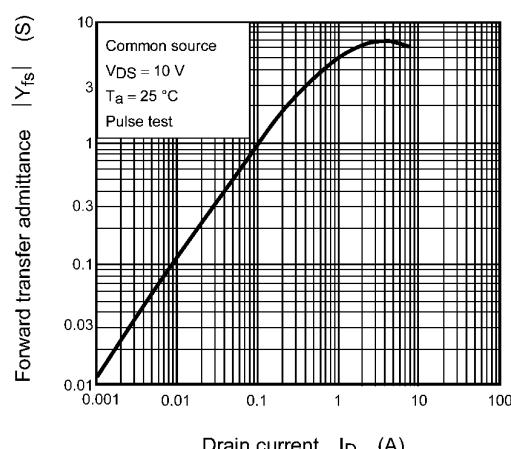


Fig. 8.8  $|Y_{fs}|$  -  $I_D$

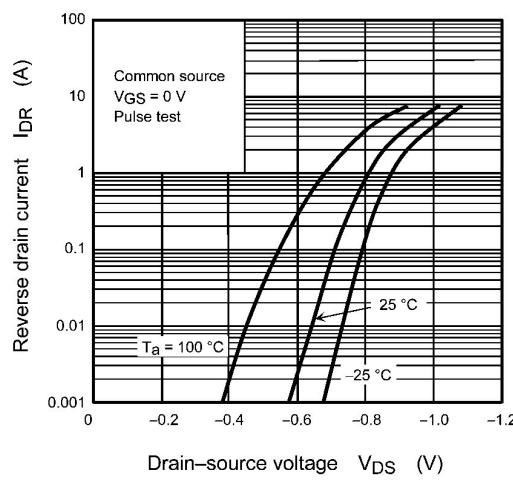


Fig. 8.9  $I_{DR}$  -  $V_{DS}$

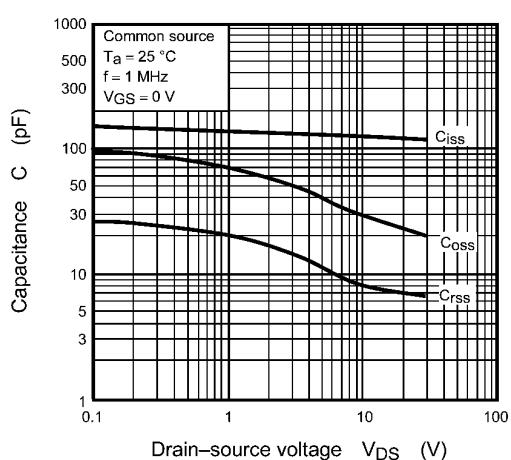


Fig. 8.10  $C$  -  $V_{DS}$

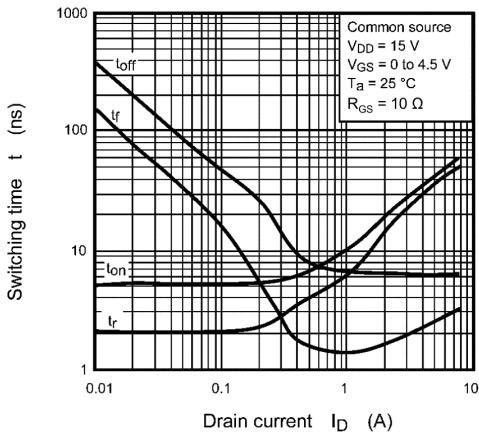


Fig. 8.11  $t$  -  $I_D$

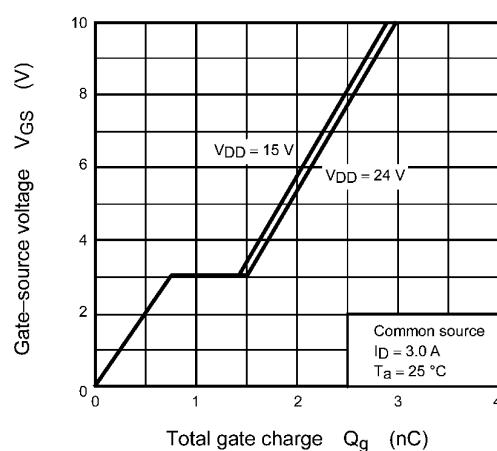


Fig. 8.12 Dynamic Input/Output Characteristics

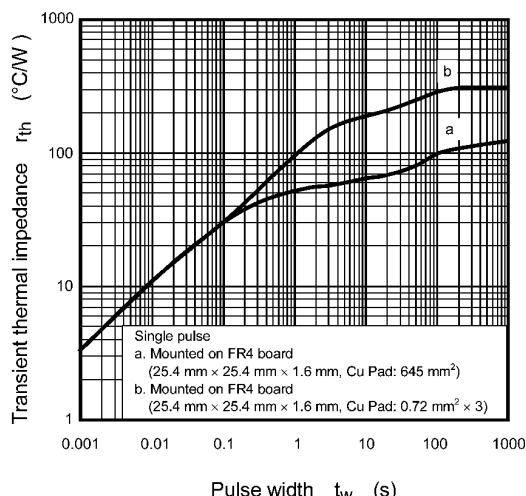


Fig. 8.13  $r_{th}$  -  $t_w$

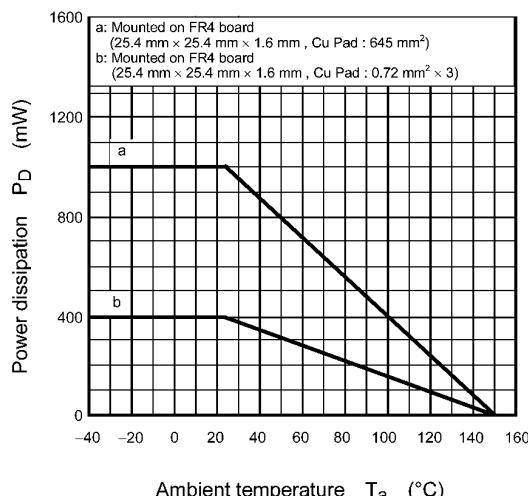


Fig. 8.14  $P_D$  -  $T_a$

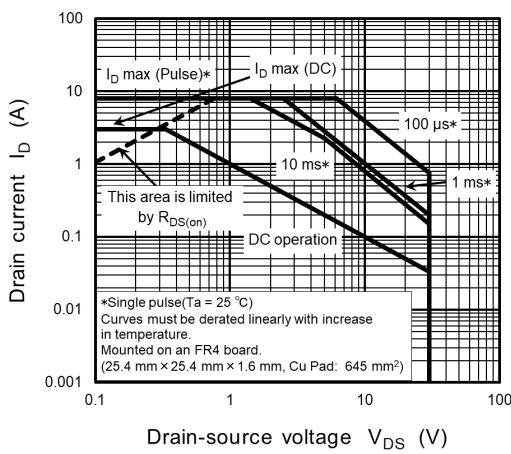
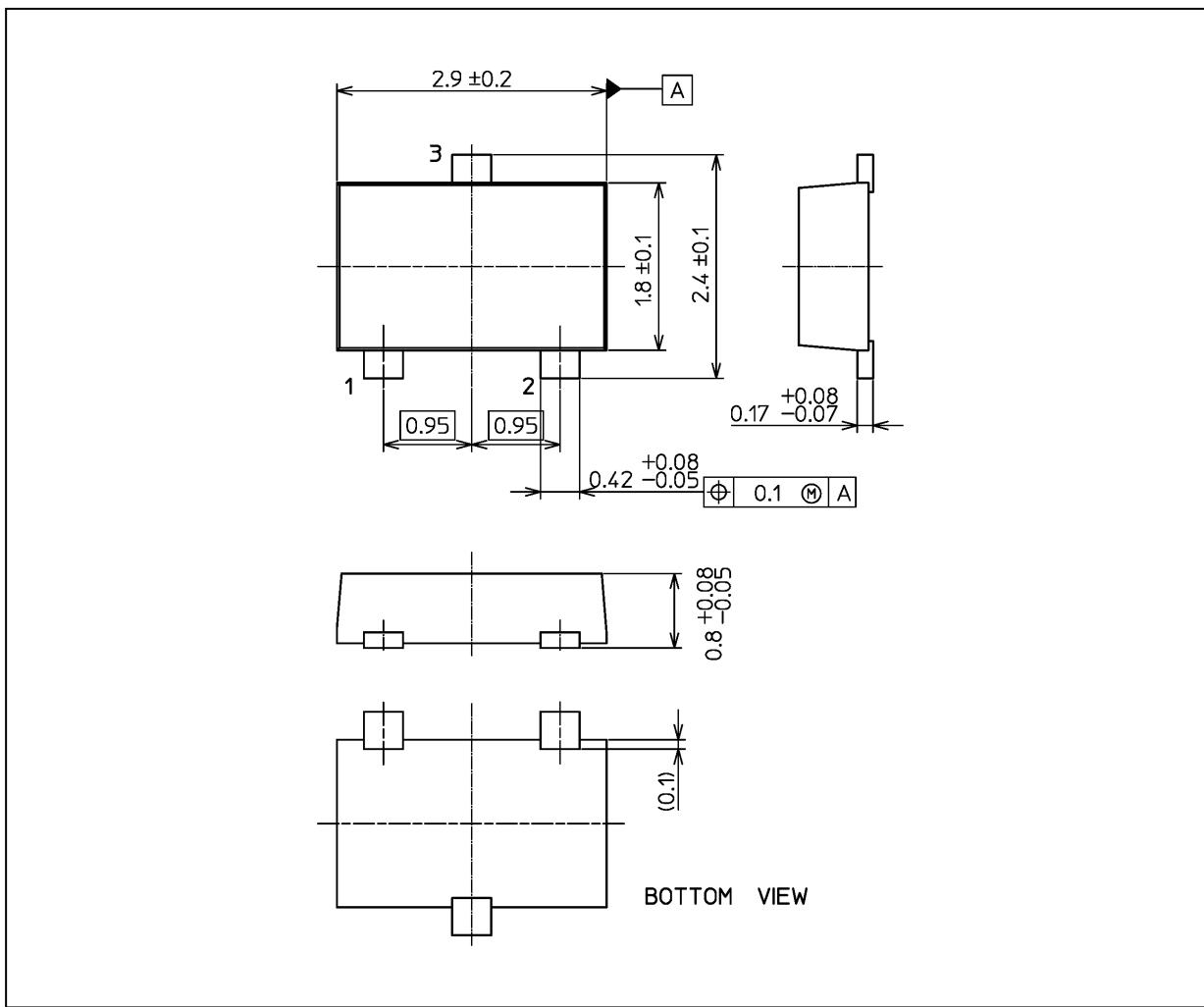


Fig. 8.15 Safe Operating Area

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

**Package Dimensions**

Unit: mm



Weight: 0.011 g (typ.)

Package Name(s)
Nickname: SOT-23F

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